

NHD-0224WH-ATDI-JT#

Character Liquid Crystal Display Module

NHD-	Newhaven Display
0224-	2 lines x 24 characters
WH-	Display Type: Character
A-	Model
T-	White LED Backlight
D-	FSTN- Negative (double film)
I-	Transmissive, Wide Temp. 6:00 view
JT#-	English and Japanese standard font
	RoHS Compliant

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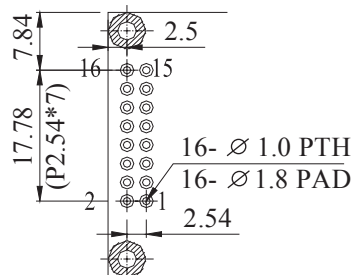
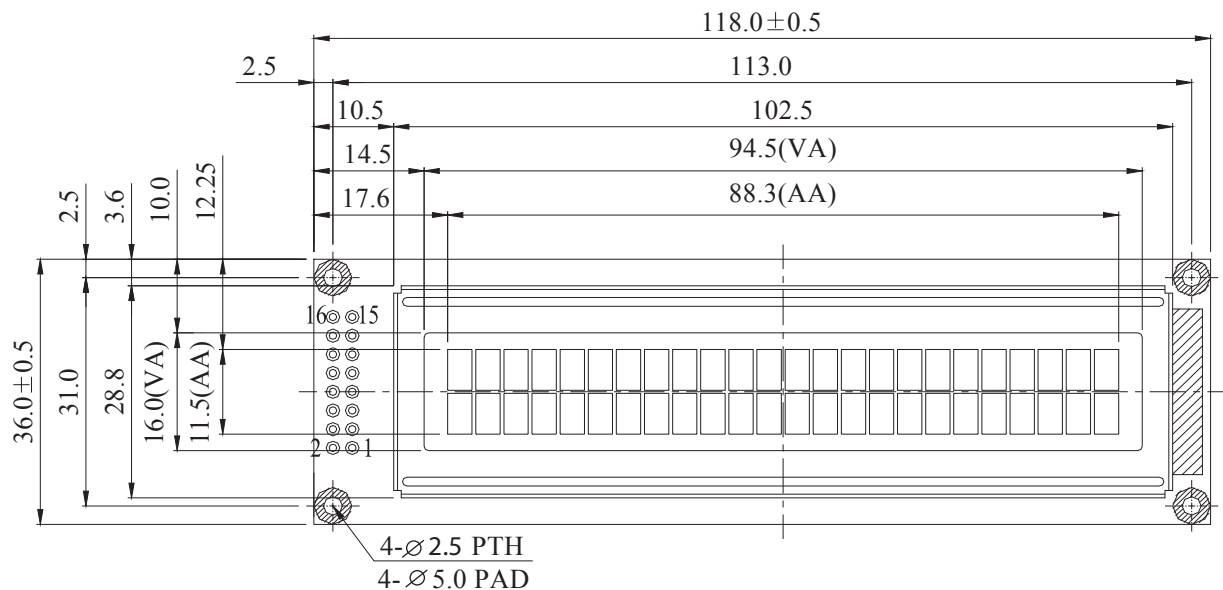
Document Revision History

Revision	Date	Description	Changed by
0	7/24/2009	Initial Release	-
1	7/27/2009	User Guide Reformat	BE
2	11/2/2009	Block Diagram Revision	BE
3	5/20/2011	Controller information updated	AK
4	6/8/2011	Mechanical drawing updated	BE

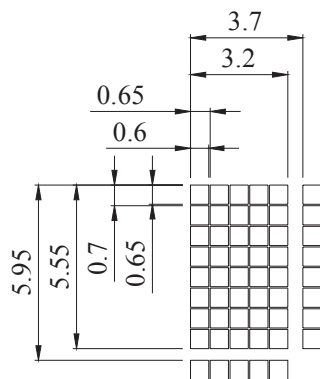
Functions and Features

- 2 lines x 24 characters
- Built-in controller (ST7066U)
- +5.0V power supply
- 1/16 duty, 1/5 bias

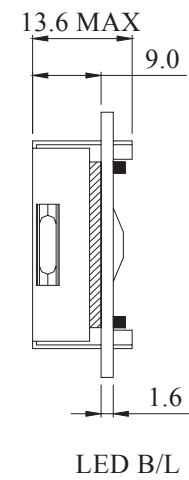
Mechanical Drawing



PIN DETAIL
SCALE 1/1



DOT SIZE
SCALE 5/1



PIN NO.	SYMBOL
1	Vss
2	Vdd
3	Vo
4	RS
5	R/W
6	E
7	DB0
8	DB1
9	DB2
10	DB3
11	DB4
12	DB5
13	DB6
14	DB7
15	LED+
16	LED-

Newhaven Display

NHD-0224WH-ATDI-JT#

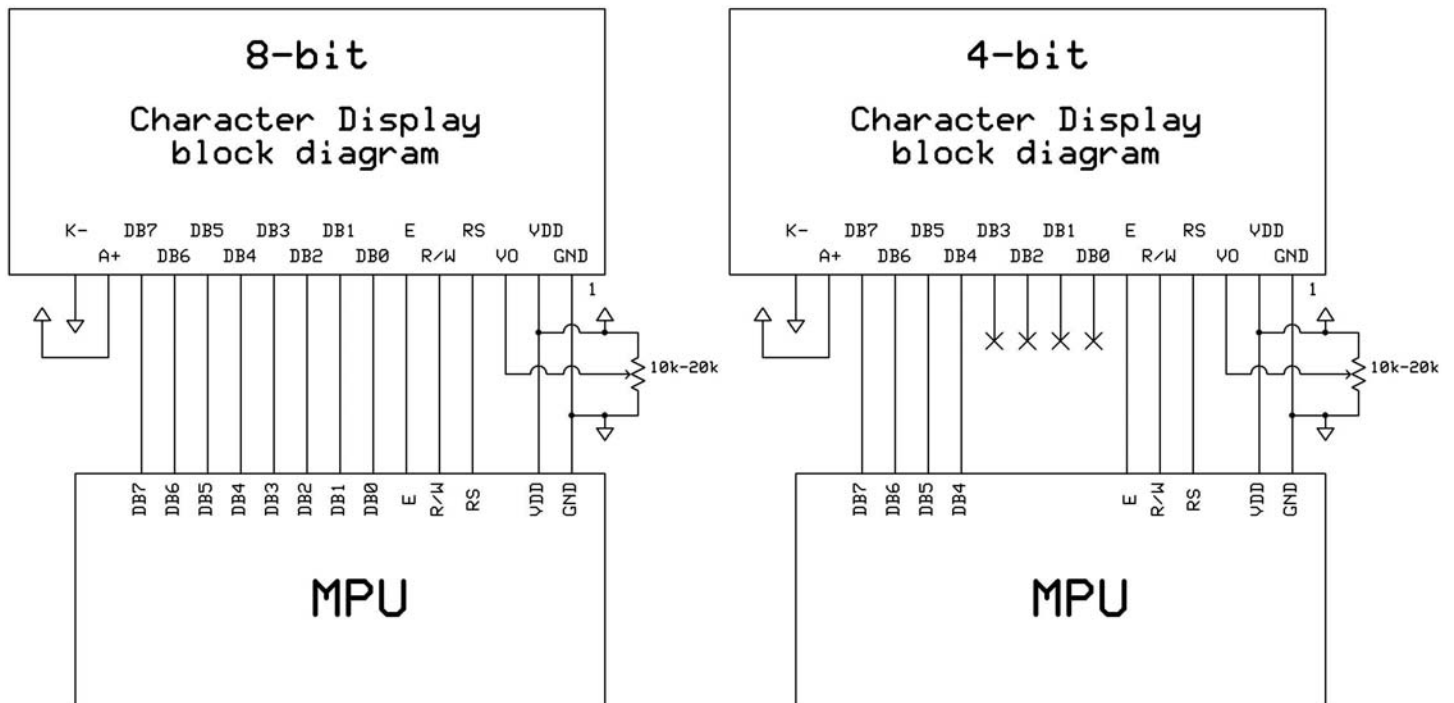
Pin Description and Wiring Diagram

Pin No.	Symbol	External Connection	Function Description
1	V_{SS}	Power Supply	Ground
2	V_{DD}	Power Supply	Supply Voltage for logic (5.0V)
3	V_0	Adj Power Supply	Power supply for contrast (approx. 0.5V)
4	RS	MPU	Register select signal. RS=0: Command, RS=1: Data
5	R/W	MPU	Read/Write select signal, R/W=1: Read R/W: =0: Write
6	E	MPU	Operation enable signal. Falling edge triggered.
7-10	DB0-DB3	MPU	Four low order bi-directional three-state data bus lines. These four are not used during 4-bit operation.
11-14	DB4 – DB7	MPU	Four high order bi-directional three-state data bus lines.
15	LED+	Power Supply	Power supply for LED Backlight (+3.5V)
16	LED-	Power Supply	Ground for Backlight

Recommended LCD connector: 2.54mm pitch, 16-pin dual-row

Backlight connector: -

Mates with: -



Electrical Characteristics

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Operating Temperature Range	Top	Absolute Max	-20	-	+70	°C
Storage Temperature Range	Tst	Absolute Max	-30	-	+80	°C
Supply Voltage	VDD		4.5	5.0	5.5	V
Supply Current	IDD	VDD=5.0V	1.0	1.2	1.5	mA
Supply for LCD (contrast)	VDD-V0	Ta=25°C	3.8	4.5	5.5	V
"H" Level input	Vih		0.7	-	VDD	V
"L" Level input	Vil		Vss	-	0.6	V
"H" Level output	Voh		3.9	-	-	V
"L" Level output	Vol		-	-	0.4	V
Backlight Supply Voltage	Vled	-	3.4	3.5	3.6	V
Backlight Supply Current	Iled	Vled=3.5V	28.8	32	50	mA
Backlight Lifetime		Iled=32	-	50,000	-	Hrs

Optical Characteristics

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Viewing Angle – Vertical (top)	AV	Cr ≥ 2	-	25	-	°
Viewing Angle – Vertical (bottom)	AV	Cr ≥ 2	-	70	-	°
Viewing Angle – Horizontal (left)	AH	Cr ≥ 2	-	30	-	°
Viewing Angle – Horizontal (right)	AH	Cr ≥ 2	-	30	-	°
Contrast Ratio	Cr		-	2	-	-
Response Time (rise)	Tr	-	-	120	150	ms
Response Time (fall)	Tf	-	-	120	150	ms

Controller Information

Built-in ST7066U. Download specification at http://www.newhavendisplay.com/app_notes/ST7066U.pdf

Display Character Address Code

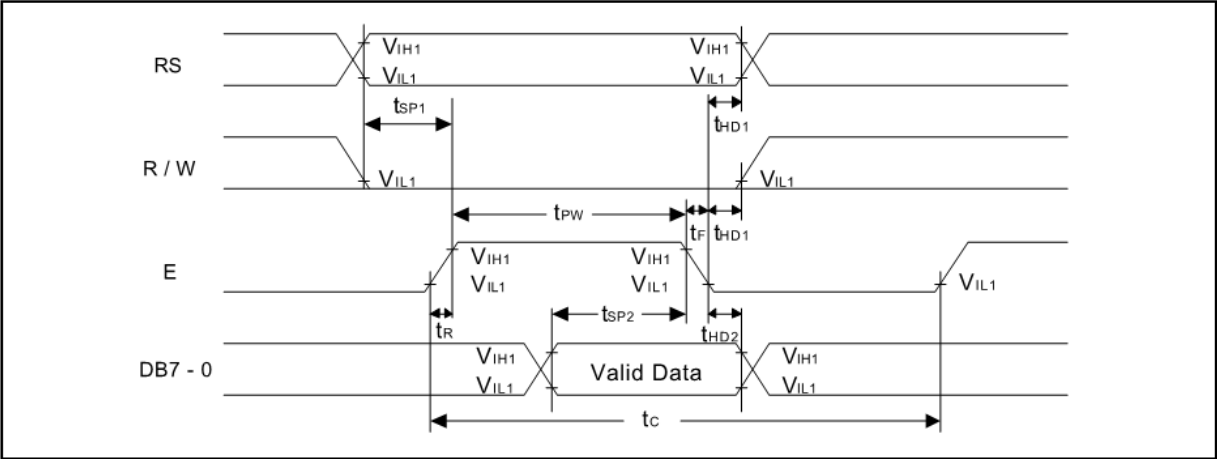
Character located	1	2	3	4	5	6	-----	19	20	21	22	23	24
DDRAM address	00	01	02	03	04	05	-----	12	13	14	15	16	17
DDRAM address	40	41	42	43	44	45	-----	52	53	54	55	56	57

Table of Commands

Instruction	Instruction Code										Description	Execution time (fosc=270Khz)
	RS	R/W	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0		
Clear Display	0	0	0	0	0	0	0	0	0	1	Write "00H" to DDRAM and set DDRAM address to "00H" from AC	1.53ms
Return Home	0	0	0	0	0	0	0	0	1	—	Set DDRAM address to "00H" from AC and return cursor to its original position if shifted. The contents of DDRAM are not changed.	1.53ms
Entry Mode Set	0	0	0	0	0	0	0	1	I/D	SH	Assign cursor moving direction and enable the shift of entire display.	39 μ s
Display ON/OFF Control	0	0	0	0	0	0	1	D	C	B	Set display (D), cursor (C), and blinking of cursor (B) on/off control bit.	39 μ s
Cursor or Display Shift	0	0	0	0	0	1	S/C	R/L	—	—	Set cursor moving and display shift control bit, and the direction, without changing of DDRAM data.	39 μ s
Function Set	0	0	0	0	1	DL	N	F	—	—	Set interface data length (DL:8-bit/4-bit), numbers of display line (N:2-line/1-line) and, display font type (F:5x11 dots/5x8 dots)	39 μ s
Set CGRAM Address	0	0	0	1	AC5	AC4	AC3	AC2	AC1	AC0	Set CGRAM address in address counter.	39 μ s
Set DDRAM Address	0	0	1	AC6	AC5	AC4	AC3	AC2	AC1	AC0	Set DDRAM address in address counter.	39 μ s
Read Busy Flag and Address	0	1	BF	AC6	AC5	AC4	AC3	AC2	AC1	AC0	Whether during internal operation or not can be known by reading BF. The contents of address counter can also be read.	0 μ s
Write Data to RAM	1	0	D7	D6	D5	D4	D3	D2	D1	D0	Write data into internal RAM (DDRAM/CGRAM).	43 μ s
Read Data from RAM	1	1	D7	D6	D5	D4	D3	D2	D1	D0	Read data from internal RAM (DDRAM/CGRAM).	43 μ s

Timing Characteristics

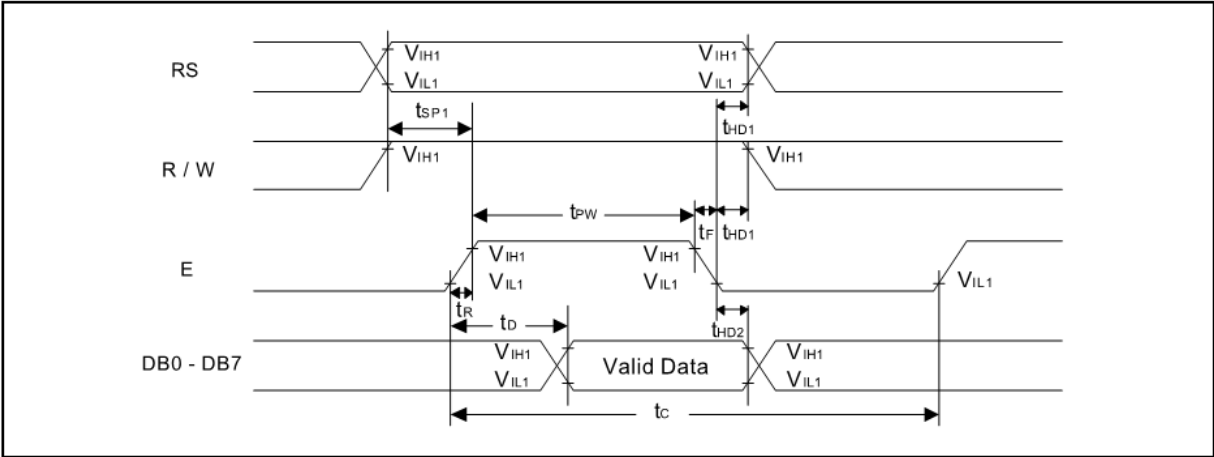
Read mode timing diagram



Ta=25°C, VDD=5.0V

Item	Symbol	Min	Typ	Max	Unit
Enable cycle time	T _C	1200	—	—	ns
Enable pulse width	T _{PW}	140	—	—	ns
Enable rise/fall time	T _R , T _F	—	—	25	ns
Address set-up time (RS, R/W to E)	t _{AS}	0	—	—	ns
Address hold time	t _{AH}	10	—	—	ns
Data set-up time	t _{DSW}	40	—	—	ns
Data hold time	t _H	10	—	—	ns

Read mode timing diagram



Built-in Font Table

Upper 4 bit Lower 4 bit	LLLL	LLH	LLHL	LLHH	LHLL	LHLH	LHHL	LHHH	HLLL	HLLH	HLHL	HLHH	HHLL	HHLH	HHHL	HHHH
LLLL	CG RAM (1)			0	1	2	3	4				5	6	7	8	9
LLH	(2)		!	A	B	C	D	E			F	G	H	I	J	K
LLHL	(3)		"	Z	R	r				T	U	V	X	Y		
LLHH	(4)		#	3	S	s				J	ウ	テ	セ	エ		
LHLL	(5)		\$	4	O	T	t			\	エ	ト	ト	ト	ト	ト
LHLH	(6)		%	5	E	U	u			"	オ	タ	エ	セ	エ	セ
LHHL	(7)		&	6	F	V	v			サ	カ	ニ	ヨ	ロ	ロ	ロ
LHHH	(8)		'	7	G	W	w			ア	ホ	ア	ウ	ロ	ロ	ロ
HLLL	(1)		(	G	H	X	x			ノ	ウ	ホ	リ	リ	リ	リ
HLLH	(2)		)	9	I	V	i			ウ	テ	リ	リ	リ	リ	リ
HLHL	(3)		*	H	J	Z	z			エ	コ	リ	リ	リ	リ	リ
HLHH	(4)		+	H	K	K	K			オ	サ	ロ	ロ	ロ	ロ	ロ
HHLL	(5)		,	<	L	*	I			ホ	ウ	ウ	ウ	ホ	ホ	ホ
HHLH	(6)		-	=	M	J	m			エ	ス	リ	リ	ホ	ホ	ホ
HHHL	(7)		.	>	N	^	n			ヨ	セ	ホ	ホ	ホ	ホ	ホ
HHHH	(8)		/	?	O	_	o			ウ	ウ	ウ	ウ	ウ	ウ	ウ

Example Initialization Program

4-bit:

```
void command(char i)
{
    P1 = i;
    D_I = 0;           //Send Instruction
    R_W = 0;
    Nybble();
    i = i<<4;
    P1 = i;
    Nybble();
}
void write(char i)
{
    P1 = i;
    D_I = 1;           //Send Data
    R_W = 0;
    Nybble();
    i = i<<4;
    P1 = i;
    Nybble();
}
void Nybble()
{
    E = 1;
    Delayms(10);       //enable pulse width >= 300ns
    E = 0;
}

void init()
{
    P1 = 0;
    P3 = 0;
    Delayms(30);
    P1 = 0x30;          //Wake up
    Delayms(100);
    Nybble();
    Delayms(100);
    Nybble();
    Delayms(10);
    Nybble();           //Wake up three times
    Delayms(10);
    P1= 0x20;           //Function set: 4-bit
    Nybble();
    command(0x28);       //Function set: 4-bit/2-line
    command(0x10);       //Set cursor
    command(0x0F);       //Display ON; Blinking cursor
    command(0x06);       //Entry Mode set
}
```

8-bit:

```
void command(char i)
{
    P1 = i;
    D_I =0;                                //Send Instruction
    R_W =0;
    E = 1;
    Delayms(1);
    E = 0;
}
void write(char i)
{
    P1 = i;
    D_I =1;                                //Send Data
    R_W =0;
    E = 1;
    Delayms(1);
    E = 0;
}
void init()
{
    E = 0;
    Delayms(5);
    command(0x30);                          //Wake up
    Delayms(100);
    command(0x30);
    Delayms(10);
    command(0x30);                          //Wake up three times
    Delayms(10);
    command(0x38);                          //Function set: 8-bit/2-line
    command(0x10);                          //Set cursor
    command(0x0c);                          //Display ON; Cursor ON
    command(0x06);                          //Entry mode set
}
```

Quality Information

Test Item	Content of Test	Test Condition	Note
High Temperature storage	Endurance test applying the high storage temperature for a long time.	+80°C , 200hrs	2
Low Temperature storage	Endurance test applying the low storage temperature for a long time.	-30°C , 200hrs	1,2
High Temperature Operation	Endurance test applying the electric stress (voltage & current) and the high thermal stress for a long time.	+70°C 200hrs	2
Low Temperature Operation	Endurance test applying the electric stress (voltage & current) and the low thermal stress for a long time.	-20°C , 200hrs	1,2
High Temperature / Humidity Operation	Endurance test applying the electric stress (voltage & current) and the high thermal with high humidity stress for a long time.	+60°C , 90% RH , 96hrs	1,2
Thermal Shock resistance	Endurance test applying the electric stress (voltage & current) during a cycle of low and high thermal stress.	-20°C,30min -> 25°C,5min -> 70°C,30min = 1 cycle 10 cycles	
Vibration test	Endurance test applying vibration to simulate transportation and use.	10-55Hz , 15mm amplitude. 60 sec in each of 3 directions X,Y,Z For 15 minutes	3
Static electricity test	Endurance test applying electric static discharge.	VS=800V, RS=1.5kΩ, CS=100pF One time	

Note 1: No condensation to be observed.

Note 2: Conducted after 4 hours of storage at 25°C, 0%RH.

Note 3: Test performed on product itself, not inside a container.

Precautions for using LCDs/LCMs

See Precautions at www.newhavendisplay.com/specs/precautions.pdf

Warranty Information and Terms & Conditions

http://www.newhavendisplay.com/index.php?main_page=terms

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

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